National Semiconductor

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CD4099BM/CD4099BC 8-Bit Addressable Latch

General Description

The CD4099B is an 8-bit addressable latch with three address inputs (A0–A2), an active low enable input ($\overline{E}$), active high clear input (CL), a data input (D), and eight outputs (Q0–Q7).

Data is entered into a particular bit in the latch when that bit is addressed by the address inputs and the enable ($\overline{E}$) is low. Data entry is inhibited when enable ($\overline{E}$) is high.

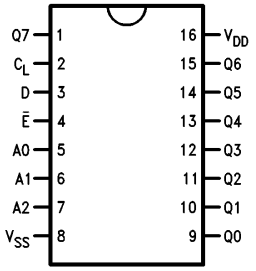
When clear (CL) and enable ($\overline{E}$) are high, all outputs are low. When clear (CL) is high and enable ($\overline{E}$) is low, the channel demultiplexing occurs. The bit that is addressed has an active output which follows the data input while all unaddressed bits are held low. When operating in the addressable latch mode ($\overline{E}$ = CL = low), changing more than one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode ($\overline{E}$ = high, CL = low).

Features

- Wide supply voltage range — 3.0V to 15V
- High noise immunity — 0.45 V_{DD} (typ.)
- Low power TTL compatibility — fan out of 2 driving 74L or 1 driving 74LS
- Serial to parallel capability
- Storage register capability
- Random (addressable) data entry
- Active high demultiplexing capability
- Common active high clear

Connection Diagram

CD4099B
Dual-In-Line Package



TL/F/5984–1

Top View

Order Number CD4099B

Truth Table

Mode Selection				
$\overline{E}$	CL	Addressed Latch	Unaddressed Latch	Mode
L	L	Follows Data	Holds Previous Data	Addressable Latch
H	L	Holds Previous Data	Holds Previous Data	Memory
L	H	Follows Data	Reset to "0"	Demultiplexer
H	H	Reset to "0"	Reset to "0"	Clear

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD})	-0.5 to $+18$ V_{DC}
Input Voltage (V_{IN})	-0.5 to V_{DD} $+0.5$ V_{DC}
Storage Temperature Range (T_S)	$-65°C$ to $+150°C$
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (T_L) (Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD})	3.0 to 15 V_{DC}
Input Voltage (V_{IN})	0 to V_{DD} V_{DC}
Operating Temperature Range (T_A)	
CD4099BM	$-55°C$ to $+125°C$
CD4099BC	$-40°C$ to $+85°C$

DC Electrical Characteristics CD4099BM (Note 2)

Symbol	Parameter	Conditions	$-55°C$		$+25°C$			$+125°C$		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		5.0		0.02	5.0		150	μA
		$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		10		0.02	10		300	μA
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		20		0.02	20		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| \leq 1\ \mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| \leq 1\ \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5.0		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$		1.5		2.25	1.5		1.5	V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$		3.0		4.5	3.0		3.0	V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$	3.5		3.5	2.75		3.5		V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$	7.0		7.0	5.5		7.0		V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$	11.0		11.0	8.25		11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V$, $V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V$, $V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 4.6V$	-0.64		-0.51	-0.88		-0.36		mA
		$V_{DD} = 10V$, $V_O = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V$, $V_O = 13.5V$	-4.2		-3.4	-8.8		-2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V$, $V_{IN} = 0V$		-0.10		-10^{-5}	-0.10		-1.0	μA
		$V_{DD} = 15V$, $V_{IN} = 15V$		0.10		10^{-5}	0.10		1.0	μA

DC Electrical Characteristics CD4099BC (Note 2)

Symbol	Parameter	Conditions	$-40°C$		$+25°C$			$+85°C$		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		20		0.02	20		150	μA
		$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		40		0.02	40		300	μA
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		80		0.02	80		600	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| \leq 1\mu A$								
		$V_{DD} = 5V$		0.05		0	0.05		0.05	V
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| \leq 1\ \mu A$								
		$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$		1.5		2.25	1.5		1.5	V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$		3.0		4.5	3.0		3.0	V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$		4.0		6.75	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$	3.5		3.5	2.75		3.5		V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$	7.0		7.0	5.5		7.0		V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$	11.0		11.0	8.25		11.0		V

DC Electrical Characteristics CD4099BC (Note 2) (Continued)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{OL}	Low Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.30		-10^{-5}	−0.30		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.30		10^{-5}	0.30		1.0	μA

AC Electrical Characteristics*

T_A = 25°C, C_L = 50 pF, R_L = 200k, Input t_r = t_f = 20 ns, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{PHL}, t_{PLH}	Propagation Delay Data to Output	V_{DD} = 5V		200	400	ns
		V_{DD} = 10V		75	150	ns
		V_{DD} = 15V		50	100	ns
t_{PLH}, t_{PHL}	Propagation Delay Enable to Output	V_{DD} = 5V		200	400	ns
		V_{DD} = 10V		80	160	ns
		V_{DD} = 15V		60	120	ns
t_{PHL}	Propagation Delay Clear to Output	V_{DD} = 5V		175	350	ns
		V_{DD} = 10V		80	160	ns
		V_{DD} = 15V		65	130	ns
t_{TLH}, t_{THL}	Propagation Delay Address to Output	V_{DD} = 5V		225	450	ns
		V_{DD} = 10V		100	200	ns
		V_{DD} = 15V		75	150	ns
t_{THL}, t_{TLH}	Transition Time (Any Output)	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
T_{WH}, T_{WL}	Minimum Data Pulse Width	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
t_{WH}, t_{WL}	Minimum Address Pulse Width	V_{DD} = 5V		200	400	ns
		V_{DD} = 10V		100	200	ns
		V_{DD} = 15V		65	125	ns
t_{WH}	Minimum Clear Pulse Width	V_{DD} = 5V		75	150	ns
		V_{DD} = 10V		40	75	ns
		V_{DD} = 15V		25	50	ns
t_{SU}	Minimum Set-Up Time Data to E	V_{DD} = 5V		40	80	ns
		V_{DD} = 10V		20	40	ns
		V_{DD} = 15V		15	30	ns
t_H	Minimum Hold Time Data to E	V_{DD} = 5V		60	120	ns
		V_{DD} = 10V		30	60	ns
		V_{DD} = 15V		25	50	ns
t_{SU}	Minimum Set-Up Time Address to E	V_{DD} = 5V		−15	50	ns
		V_{DD} = 10V		0	30	ns
		V_{DD} = 15V		0	20	ns
t_H	Minimum Hold Time Address to E	V_{DD} = 5V		−50	15	ns
		V_{DD} = 10V		−20	10	ns
		V_{DD} = 15V		−15	5	ns
C_{PD}	Power Dissipation Capacitance	Per Package (Note 4)		100		pF
C_{IN}	Input Capacitance	Any Input		5.0	7.5	pF

*AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Condtions" and "Electrical Characteristics" provide conditions for actual device operation.

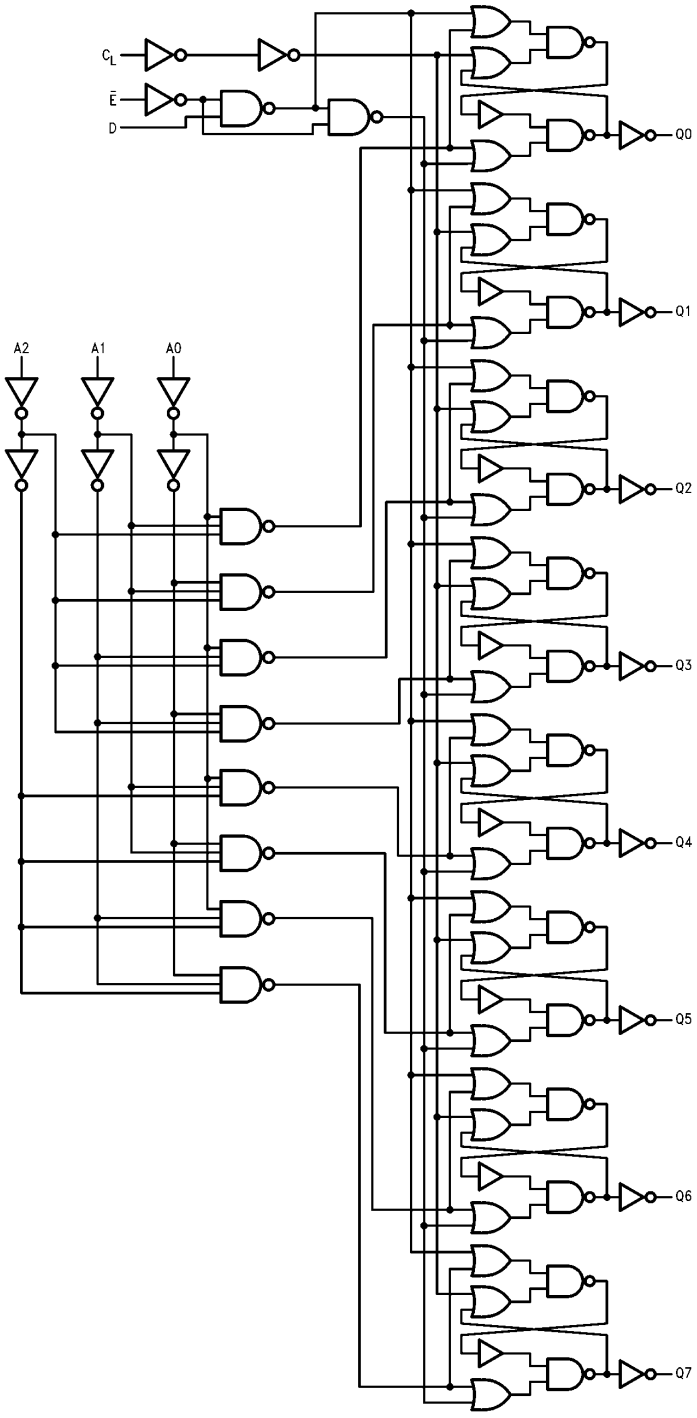
Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

Note 4: Dynamic power dissipation (P_D) is given by: $P_D = (C_{PD} + C_L) V_{CC}^2 f + P_Q$; where C_L = load capacitance; f = frequency of operation; for further details, see application note AN-90, "54C/74C Family Characteristics".

Logic Diagram

CD4099B



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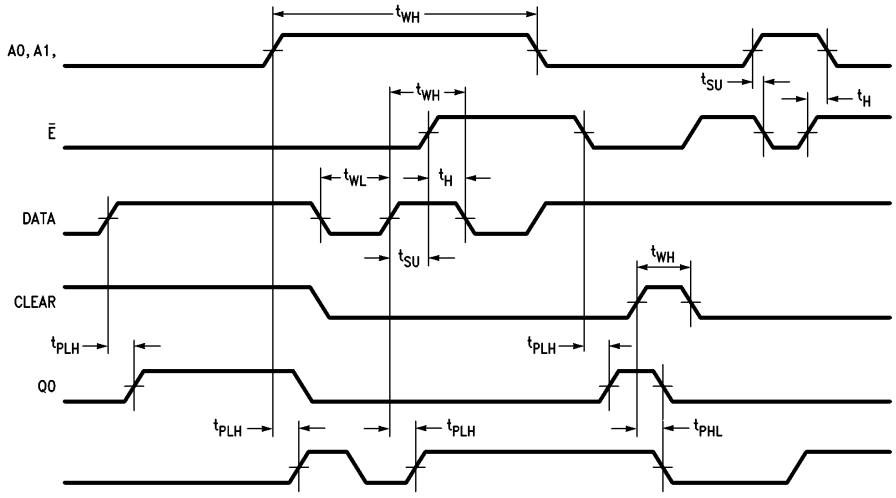
Switching Time Waveforms



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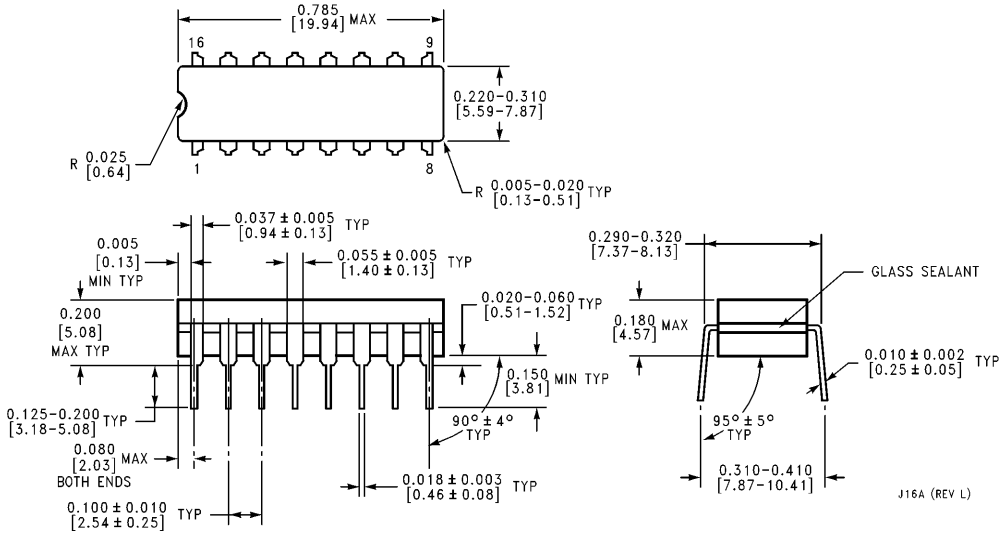
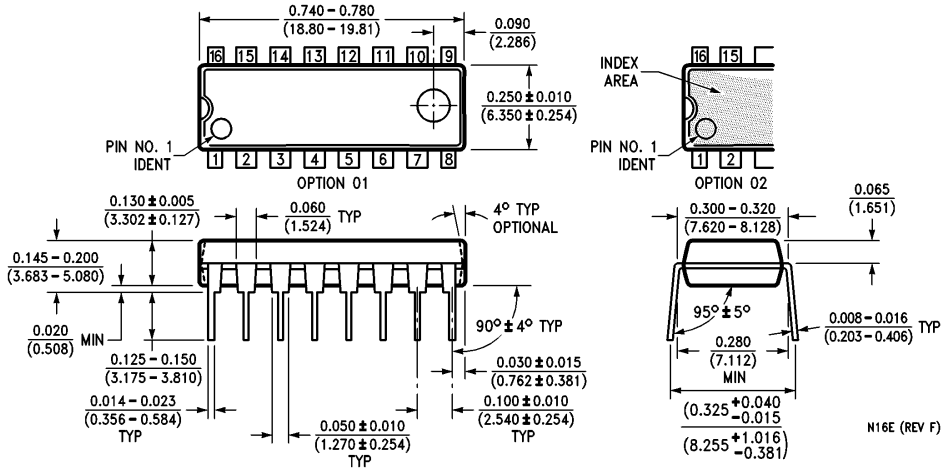
Physical Dimensions inches (millimeters)



Ceramic Dual-In-Line Package (J)
Order Number CD4099BMJ or CD4099BCJ
NS Package Number J16A

Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number CD4099BMN or CD4099BCN
NS Package Number N16E

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National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408